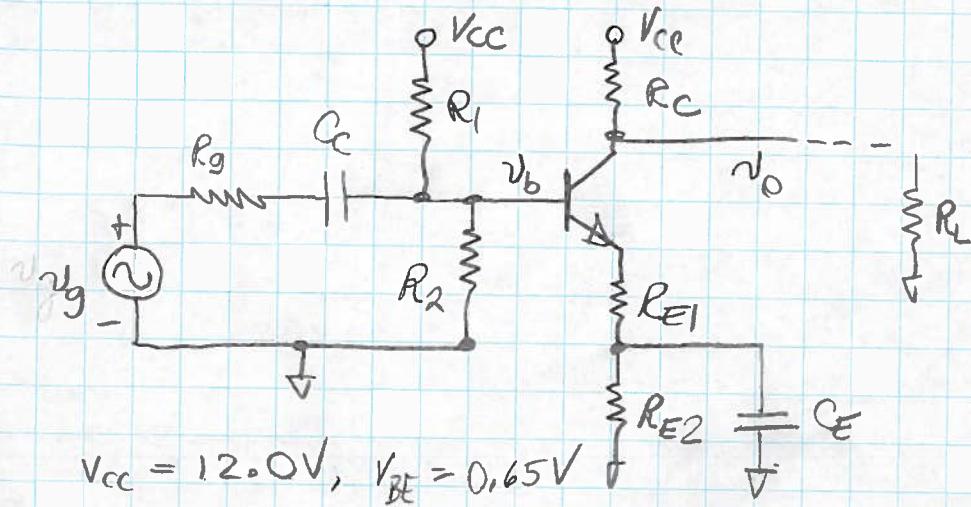


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$$R'_C = R_C \parallel R_L$$

Compute gain of
bjt amp stage from
voltage source v_g , to
output v_o , at load.

We will also compute "beta-dependency", i.e. gain variation w/ beta.

Let $h_{FE} = \text{min value of } 50$, $R_{E1} = 100\Omega$, $R_{E2} = 1.0k\Omega$, $R_1 = 10k\Omega$,

$B_2 = 4.7k\Omega$, $R_C = 2.2k\Omega$, $R_L = 10k\Omega$, $R_g = 1.0k\Omega$. C_E and C_C are

large enough to be shorts at the signal frequency involved.

dc bias $R_E = R_{E1} + R_{E2} = 0.10 + 1.0 = 1.10 k\Omega$. R'_E is the

value of R_E seen from the base: $R'_E = (h_{FE} + 1) R_E = (50 + 1)(1.10 k\Omega)$

$R'_E = 56.1k\Omega$. This value is in parallel w/ B_2 , so that R'_2 is

$$R_2 \parallel R'_E = 4.7k \parallel 56.1k = 4.337k\Omega. V'_B = V_{CC} \frac{R'_2}{R_1 + R'_2}$$

$$V'_B = (12.0V) \frac{4.337k\Omega}{10k\Omega + 4.337k\Omega} = 3.630V; V''_B = V_{BE} \frac{R_1 \parallel R_2}{R'_E + (R_1 \parallel R_2)}$$

$$V''_B = (0.65V) \frac{10k\Omega \parallel 4.7k\Omega}{56.1k\Omega + (10k\Omega \parallel 4.7k\Omega)} = 0.0350V, \text{ so that } V_B = V'_B + V''_B$$

$$V_B = 3.630V + 0.0350V = 3.665V. V_E = V_B - V_{BE} = 3.665 - 0.65V$$

$$V_E = 3.015V. I_E = \frac{V_E}{R_E} = \frac{3.015V}{1.10k\Omega} = 2.741mA = \underline{\underline{I_E}}$$

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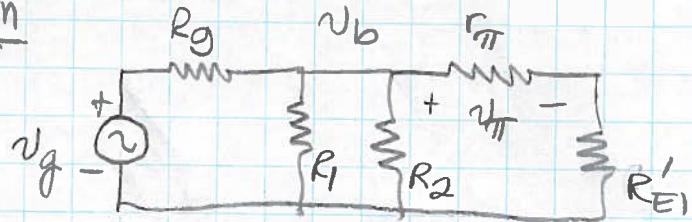
$$I_C = \alpha I_E, \quad \alpha = \frac{\beta}{\beta+1} = \frac{50}{50+1} = 0.980, \quad I_C = 0.980(2.741 \text{ mA})$$

$I_C = 2.687 \text{ mA}$; at $T = 25^\circ\text{C}$, 298°K , $V_T = \frac{kT}{q}$, so that

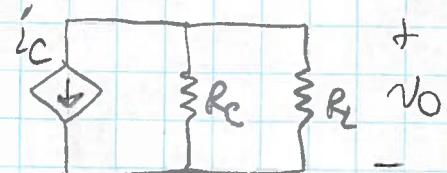
$$V_T = \frac{(1.3806 \times 10^{-23} \text{ J}/\text{ok})(298^\circ\text{K})}{1.602 \times 10^{-19} \text{ C}} = 0.02568 \text{ V.}$$

$$g_m = \frac{I_C}{V_T} = \frac{2.687 \text{ mA}}{25.68 \text{ mV}} = 0.10463 \text{ S.}$$

ac signal gain



$$i_c = g_m v_{\pi} = h_{fe} i_b$$



$$v_o = -i_c (R_c \parallel R_L), \quad i_c = g_m v_{\pi}, \quad \text{but } r_{\pi} \text{ is needed to know } v_{\pi}.$$

$$r_{\pi} = \frac{h_{fe}}{g_m}, \quad h_{fe} \approx h_{FE} \text{ for bjt device with very high } f_T.$$

$$r_{\pi} = \frac{50}{0.10463 \text{ S.}} = 477.87 \Omega, \quad R'_{EI} = (h_{fe} + 1) R_{EI} = (51)(0.10 \text{ k}\Omega)$$

$$R'_{EI} = 5.10 \text{ k}\Omega; \quad v_{\pi} = v_b \frac{r_{\pi}}{R'_{EI} + r_{\pi}} = \frac{0.47787 \text{ k}\Omega}{5.1 \text{ k}\Omega + 0.47787 \text{ k}\Omega} v_b$$

$$v_{\pi} = 0.085673 v_b. \quad \text{To determine } v_b = v_g \frac{R_1 \parallel R_2 \parallel (r_{\pi} + R'_{EI})}{R_g + (R_1 \parallel R_2)(r_{\pi} + R'_{EI})}$$

$$v_b = v_g \frac{10 \parallel 4.7 \parallel (0.47787 + 5.10)}{1.0 + (10 \parallel 4.7 \parallel (0.47787 + 5.10))} = 0.67022 v_g$$

$$v_{\pi} = (0.085673)(0.67022) v_g = 0.05742 v_g.$$

$$\text{Thus } i_C = g_m v_T = (0.10463 V)(0.05742 \text{ nA}) = 0.006078 \text{ nA}$$

$$R'_C = R_C // R_E = 2.2 \text{ k}\Omega // 10 \text{ k}\Omega = 1.8033 \text{ k}\Omega, \text{ so that } i_C R'_C \\ = g_m v_T R'_C = v_0 = (0.006078 \text{ nA})(1.8033 \text{ k}\Omega) = \underline{10.960 \text{ nV}}$$

$$v_0 / v_g = \text{signal gain} = \underline{-10.960} = \text{the 10.96 value}$$

must be less than $\frac{R'_C}{R_E}$, the asymptotic limit. R'_C / R_E
 $= 1.803 \text{ k}\Omega / 0.10 \text{ k}\Omega = \underline{18.03}$, which exceeds 10.96.

$$\text{gain} = 10.96, \text{ with } h_{FE} = 50 \text{ min value.}$$

We now compute w/ $h_{FE} = 500$ max value.

$$\underline{\text{dc bias}} \quad R'_E = (h_{FE} + 1) R_E = (500 + 1)(1.10 \text{ k}\Omega) = 551.1 \text{ k}\Omega$$

$$R'_2 = R_2 // R'_E = 4.7 \text{ k}\Omega // 551.1 \text{ k}\Omega \approx 4.660 \text{ k}\Omega; \quad v'_B = V_{cc} \frac{R'_2}{R_1 + R'_2}$$

$$v'_B = (12.0V) \frac{4.660 \text{ k}\Omega}{10 \text{ k}\Omega + 4.660 \text{ k}\Omega} = 3.815V; \quad v''_B = \frac{R_1 // R_2}{R'_E + (R_1 // R_2)} V_{BE}$$

$$v''_B = (0.65V) \frac{10 \text{ k}\Omega // 4.7 \text{ k}\Omega}{551.1 \text{ k}\Omega + (10 \text{ k}\Omega // 4.7 \text{ k}\Omega)} = 0.00375V \Rightarrow v_B = v'_B + v''_B$$

$$v_B = 3.815V + 0.00375V = 3.818V; \quad V_E = v_B - V_{BE}$$

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$$V_E = 3.818V - 0.65V = 3.168V \quad I_E = \frac{V_E}{R_E} = \frac{3.168V}{10k\Omega} = 2.880 \text{ mA}$$

$$I_C = \alpha I_E = \left(\frac{500}{501}\right)(2.880 \text{ mA}) = 2.875 \text{ mA}$$

ac signal gain $g_m = \frac{I_C}{V_T} = \frac{2.875 \text{ mA}}{25.68 \text{ mV}} = 0.11194 \text{ V}$

$$r_{\pi} = \frac{h_{FE}}{g_m} = \frac{500}{0.11194 \text{ V}} = 4.4668 \text{ k}\Omega ; \quad R_{E1}' = (h_{FE} + 1)R_{E1}$$

$$R_{E1}' = (501)(0.10 \text{ k}\Omega) = 50.1 \text{ k}\Omega. \quad \frac{v_{\pi}}{v_b} = \frac{r_{\pi}}{R_{E1}' + r_{\pi}}$$

$$\frac{v_{\pi}}{v_b} = \frac{4.4668}{50.1 + 4.4668} = 0.08186 ;$$

$$\frac{v_b}{v_g} = \frac{R_1 || R_2 || (r_{\pi} + R_{E1}')}{R_g + (R_1 || R_2 || (r_{\pi} + R_{E1}'))} = \frac{10 || 4.7 || (4.4668 + 50.1)}{1.0 + (10 || 4.7 || (4.4668 + 50.1))} = 0.75126$$

$$\frac{v_{\pi}}{v_g} = \frac{v_{\pi}}{v_b} \frac{v_b}{v_g} = (0.08186)(0.75126) = 0.06150$$

$$v_o = i_C R_L' = g_m v_{\pi} R_C' \Rightarrow \frac{v_o}{v_g} = \text{gain} = -g_m R_C' \frac{v_{\pi}}{v_g}$$

$$\frac{v_o}{v_g} = -0.11194 \text{ V} (1.8033 \text{ k}\Omega)(0.06150) = -12.414 \frac{\text{V}}{\text{V}}$$

Thus h_{FE} increased by 900% ($50 \rightarrow 500$), and gain increased by 13.3%. Larger R_{E1} provides less variation.



Claude